

Features:

- 650V Schottky Diode
- Zero Reverse Recovery Current
- High Frequency Operation
- Positive Temperature Coefficient
- Temperature independent Switching

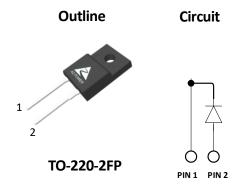
Benefits:

- Unipolar Rectifier
- Minimal switching loss
- Higher Efficiency
- Low cooling requirement

Symbol	Value	Unit
V_{RRM}	650	V
I _{F (TC=113°C)}	10	Α
Q_{C}	24	nC

Applications:

- Switch Mode Power Supply
- Booster diodes in PFC, DC/DC
- AC/DC converters



Maximum Ratings

Symbol	Parameter	Value	Unit	Test Conditions
V_R	DC Peak Reverse Voltage	650	V	T _J =25°C
V _{RRM}	Repetitive Peak Reverse Voltage	650	V	T _J =25°C
V_{RSM}	Surge Peak Reverse Voltage	650	V	T _J =25°C
I _F	Continuous Forward Current	17.5 13.5 10	А	T _C =25°C T _C =75°C T _C =113°C
I _{FRM}	Repetitive Peak Forward Surge Current	51 46	А	T_C =25°C, T_P =10ms, Half Sine Wave Tc=110°C, T_P =10ms, Half Sine Wave
I _{FSM}	Non-Repetitive Peak Forward Surge Current	67 61	А	T_C =25°C, T_P =10ms, Half Sine Wave Tc=110°C, T_P =10ms, Half Sine Wave
P _D	Power Dissipation	46 20.5	W	T _C =25°C Tc=110°C
T _{J,max}	Operating Junction Temperature	175	°C	
T _{stg}	Storage Temperature Range	-55 to 175	°C	

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Thermal characteristics

Symbol	Parameter	Min.	Тур.	Max.	Unit
R_{thJC}	Thermal resistance		3.2		°C/W

Electrical Characteristics

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Symbol	Parameter	Min.	Тур.	Max.	Unit	Test Conditions
V _{DC}	DC Blocking Voltage	650			V	I _R =100μA, T _J =25°C
V	Forward Voltage		1.6	1.8	V	I _F =10A, T _J =25°C
V _F	Forward Voltage		1.9	2.2	V	I _F =10A, T _J =175°C
	Reverse Current		1	50	μА	V _R =650V, T _J =25°C
I _R	neverse current		10	200		V _R =650V, T _J =175°C
Q_{C}	Total Capacitive Charge		24		nC	$Q_C = \int_0^{V_R} C dV$ $Tj=25 \text{ C, V}_R=400\text{ V}$
			376			V _R =1V, T _J =25°C, f=1 MHz
С	Total Capacitance		44		pF	V _R =200V, T _J =25°C, f=1 MHz
			40			V _R =400V, T _J =25°C, f=1 MHz

Typical Performance

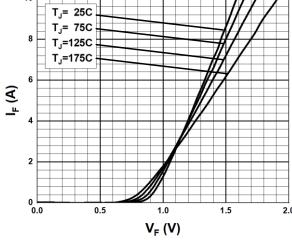


Fig. 1 Forward Characteristics

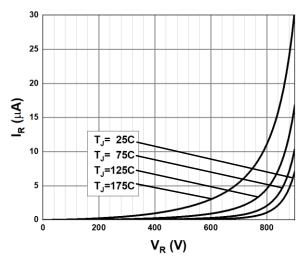


Fig. 2 Reverse Characteristics

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Typical Performance

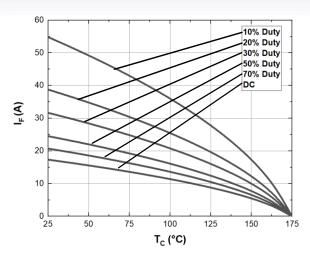


Fig. 3 Current Derating

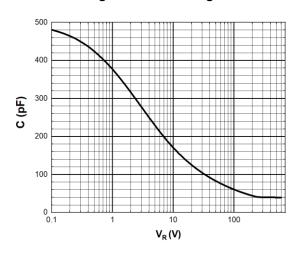


Fig. 5 Capacitance vs. Reverse Voltage

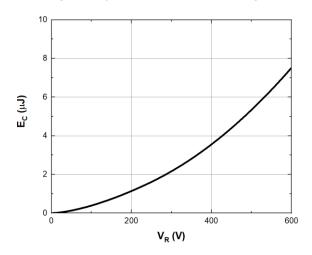


Fig. 7 Capacitance stored Energy

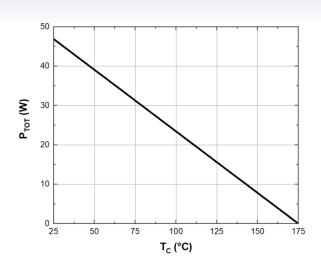


Fig. 4 Power Derating

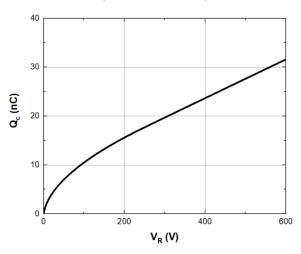
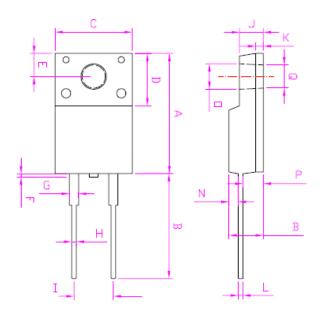


Fig. 6 Recovery Charge vs. Reverse Voltage



Package TO-220-2L (Unit: mm)



REF.DIM	DATA BOOK mm					
	NOR	MIN	MAX			
A	15.6	14.8	16.1			
В	13	12.65	13.8			
C	10	9.85	10.36			
D	6.5	4.6	6.8			
Е	3.0	2.55	3.5			
F			1			
G	1.2	1	1.45			
H	0.6	0.3	0.9			
I	5.1	4.8	5.4			
J	3.1	2.34	3.3			
K	1.0	0.55	1.3			
L	0.6	0.36	0.8			
M	4.45	4.2	4.9			
N	1.2	1.1	1.8			
О	3.3	2.9	3.5			
P	2.6	2.5	3.15			
Q	3	2.9	3.5			



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